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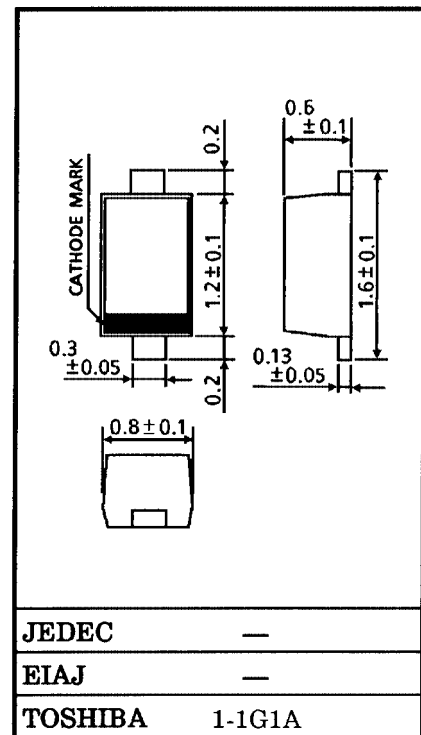
Useful for VCO/TCXO

- Small Package
- High Capacitance Ratio: $C_{1V}/C_{4V} = 3.75$ (typ.)
- Low Series Resistance : $r_s = 0.45 \Omega$ (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Reverse voltage	V_R	10	V
Junction temperature	T_j	125	°C
Storage temperature range	T_{stg}	-55~125	°C

Unit in mm



Weight 0.0014 g

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• The information contained herein is subject to change without notice.

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse voltage	V_R	$I_R = 1 \mu A$	10	—	—	V
Reverse current	I_R	$V_R = 10 V$	—	—	3	nA
Capacitance	C_{1V}	$V_R = 1 V, f = 1 MHz$	17	18	19	pF
	C_{4V}	$V_R = 4 V, f = 1 MHz$	4.25	4.8	5.43	
Capacitance ratio	C_{1V}/C_{4V}	—	3.5	3.75	—	—
Series resistance	r_s	$V_R = 1 V, f = 470 MHz$	—	0.45	0.7	Ω

Marking

